

TinyLogic HST 2-Input NOR Gate

NC7ST02

Description

The NC7ST02 is a single 2–Input high performance CMOS NOR Gate, with TTL–compatible inputs. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation. ESD protection diodes inherently guard both inputs and output with respect to the $V_{\rm CC}$ and GND rails. High gain circuitry offers high noise immunity and reduced sensitivity to input edge rate. The TTL–compatible inputs facilitate TTL to NMOS / CMOS interfacing. Device performance is similar to MM74HCT but with $^{1}/_{2}$ the output current drive of HC / HCT.

Features

- Space Saving SOT23-5, SC-74A and SC-88A 5-Lead Package
- Ultra Small MicroPak™ Leadless Package
- High Speed: $t_{PD} < 7$ ns Typ, $V_{CC} = 5$ V, $C_L = 15$ pF
- Low Quiescent Power: $I_{CC} < 1 \mu A$ Typ, $V_{CC} = 5.5 \text{ V}$
- Balanced Output Drive: 2 mA I_{OL}, -2 mA I_{OH}
- TTL-compatible Inputs
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

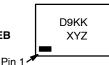


Figure 1. Logic Symbol

MARKING DIAGRAMS



SIP6 CASE 127EB





SC-74A CASE 318BQ





SOT23-5 CASE 527AH





SC-88A CASE 419A-02



D9, 8S02, T02 = Specific Device Code

KK = 2-Digit Lot Run Traceability Code
XY = 2-Digit Date Code Format
Z = Assembly Plant Code
M = Date Code*

*Date Code orientation and/or position may vary depending upon manufacturing location.

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 4 of this data sheet.

NC7ST02

Pin Configurations

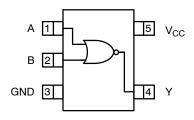


Figure 2. SOT23-5, SC-88A and SC-74A (Top View)

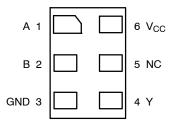


Figure 3. MicroPak (Top Through View)

PIN DESCRIPTIONS

| Pin Name | Description |
|----------|-------------|
| A, B | Inputs |
| Y | Output |
| NC | No Connect |

FUNCTION TABLE $(Y = \overline{A + B})$

| Inp | Output | |
|-----|--------|---|
| Α | В | Υ |
| L | L | Н |
| L | Н | L |
| Н | L | L |
| Н | Н | L |

H = HIGH Logic Level L = LOW Logic Level

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | | Min | Max | Unit |
|-------------------------------------|-----------------------------------------------------|------------------------------------|------|-----------------------|------|
| V _{CC} | Supply Voltage | | -0.5 | 6.5 | V |
| I _{IK} | DC Input Diode Current | V _{IN} < 0 V | = | -20 | mA |
| | | V _{IN} > V _{CC} | = | +20 | |
| V _{IN} | DC Input Voltage | | -0.5 | V _{CC} + 0.5 | V |
| I _{OK} | DC Output Diode Current | V _{OUT} < 0 V | = | -20 | mA |
| | | V _{OUT} > V _{CC} | = | +20 | |
| V _{OUT} | Output Voltage | | -0.5 | V _{CC} + 0.5 | V |
| I _{OUT} | DC Output Source or Sink Current | | = | ±12.5 | mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current per Supply Pin | | = | ±25 | mA |
| T _{STG} | Storage Temperature | | -65 | +150 | °C |
| T _J | Junction Temperature | | - | +150 | °C |
| TL | Lead Temperature (Soldering, 10 Seconds) | | - | +260 | °C |
| P _D | Power Dissipation in Still Air | SC-74A / SOT23-5 | - | 390 | mW |
| | | SC-88A | - | 332 | |
| | | MicroPak-6 | - | 812 | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

NC7ST02

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------------------|--------------------------|-------------------------|-----|-----------------|------|
| V _{CC} | Supply Voltage | | 4.5 | 5.5 | V |
| V _I | Input Voltage | | 0 | V _{CC} | V |
| V _O | Output Voltage | | 0 | V _{CC} | V |
| T _A | Operating Temperature | | -40 | +85 | °C |
| t _r , t _f | Input Rise and Fall Time | V _{CC} = 5.0 V | 0 | 10 | ns/V |
| θ_{JA} | Thermal Resistance | SC-74A / SOT23-5 | - | 320 | °C/W |
| | | SC-88A | - | 377 | |
| | | MicroPak-6 | - | 154 | |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTICAL CHARACTERISTICS

| | | | | - | Γ _A = +25°C | ; | T _A = -40 | to +85°C | |
|------------------|---------------------------|---------------------|--------------------------------------------------------------------------------------------------------------------------------|-------------|------------------------|-------------|----------------------|-------------|------|
| Symbol | Parameter | V _{CC} (V) | Conditions | Min | Тур | Max | Min | Max | Unit |
| V _{IH} | HIGH Level Input Voltage | 4.5 – 5.5 | | 2.0 | - | - | 2.0 | - | V |
| V _{IL} | LOW Level Input Voltage | 4.5 – 5.5 | | - | - | 0.8 | _ | 8.0 | V |
| V _{OH} | HIGH Level Output Voltage | 4.5 4.5 | $\begin{split} I_{OH} &= -20 \ \mu A \\ V_{IN} &= V_{IH} \ or \ V_{IL} \\ I_{OH} &= -2 \ m A \end{split}$ | 4.4 4.18 | 4.5 4.35 | - | 4.4 4.13 | - | V |
| V _{OL} | LOW Level Output Voltage | 4.5 4.5 | $\begin{split} I_{OL} &= 20 \; \mu\text{A} \\ V_{IN} &= V_{IH} \; \text{or} \; V_{IL} \\ I_{OL} &= 2 \; \text{mA} \end{split}$ | - | 0 0.10 | 0.1 0.26 | - | 0.1 0.33 | V |
| I _{IN} | Input Leakage Current | 5.5 | $0V \leq V_{IN} \leq 5.5 \ V$ | - | - | ±0.1 | _ | ±1.0 | μΑ |
| I _{CC} | Quiescent Supply Current | 5.5 | V _{IN} = V _{CC} or GND | _ | _ | 1.0 | _ | 10.0 | μΑ |
| I _{CCT} | I _{CC} per Input | 5.5 | One Input V_{IN} = 0.5 V or 2.4 V, Other Input V_{CC} or GND | . 1 | ı | 2.0 | _ | 2.9 | mA |

AC ELECTRICAL CHARACTERISTICS

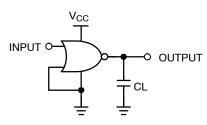
| | | | | | T _A = +25°(| | $T_A = -40$ | to +85°C | |
|-------------------------------------|------------------------------------------|---------------------|------------------------|-----|------------------------|-----|-------------|----------|------|
| Symbol | Parameter | V _{CC} (V) | Conditions | Min | Тур | Max | Min | Max | Unit |
| t _{PLH} , t _{PHL} | Propagation Delay (Figure 4, 6) | 5.0 | C _L = 15 pF | - | 3.5 | 12 | _ | - | ns |
| | | | | - | 6.3 | 17 | _ | - | |
| | | 4.5 | C _L = 50 pF | - | 6.1 | 16 | _ | 20 | |
| | | | | - | 11.7 | 27 | _ | 31 | |
| | | 5.5 | | - | 4.2 | 14 | _ | 18 | |
| | | | | - | 11.4 | 26 | - | 30 | |
| t _{TLH} , t _{THL} | Output Transition Time | 5.0 | C _L = 15 pF | - | 4 | 10 | - | - | ns |
| | (Figure 4, 6) | 4.5 | C _L = 50 pF | - | 11 | 25 | - | 31 | |
| | | 5.5 | | - | 10 | 21 | - | 26 | |
| C _{IN} | Input Capacitance | Open | | - | 2 | 10 | _ | _ | pF |
| C _{PD} | Power Dissipation Capacitance (Figure 5) | 5.0 | (Note 2) | - | 6 | _ | - | - | pF |

^{2.} C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current. Current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 5).C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CCstatic}).

^{1.} Unused inputs must be held HIGH or LOW. They may not float.

NC7ST02

AC Loading and Waveforms



 C_L includes load and stray capacitance Input PRR = 1.0 MHz; t_W = 500 ns

Figure 4. AC Test Circuit

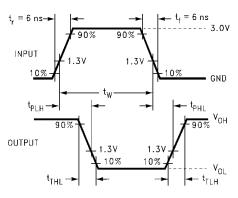
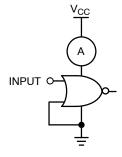


Figure 6. AC Waveforms



Input = AC Waveform;

PRR = Variable; Duty Cycle = 50%.

Figure 5. I_{CCD} Test Circuit

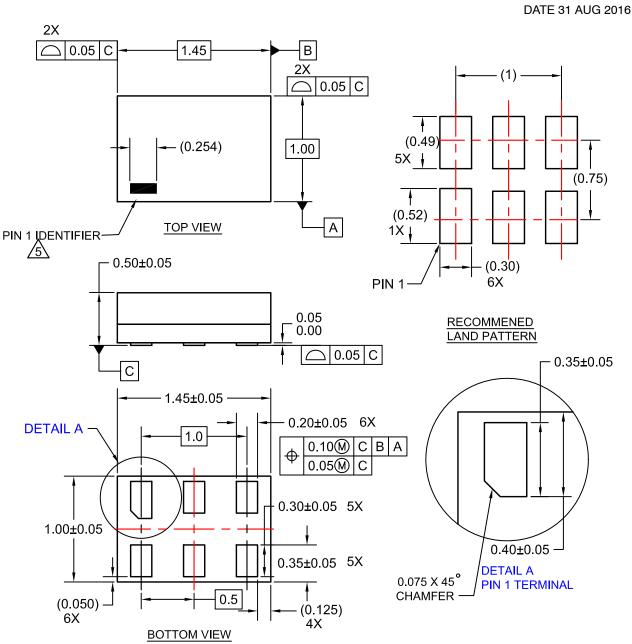
ORDERING INFORMATION

| Order Number | Top Mark | Package Description | Shipping [†] |
|-------------------|----------|---------------------|-----------------------|
| NC7ST02M5X | 8S02 | SC-74A | 3000 / Tape & Reel |
| NC7ST02M5X-L22090 | 8S02 | SOT23-5 | 3000 / Tape & Reel |
| NC7ST02P5X | T02 | SC-88A | 3000 / Tape & Reel |
| NC7ST02P5X-L22057 | T02 | SC-88A | 3000 / Tape & Reel |
| NC7ST02L6X | D9 | SIP6, MicroPak | 5000 / Tape & Reel |
| NC7ST02L6X-L22175 | D9 | SIP6, MicroPak | 5000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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NOTES:

- 1. CONFORMS TO JEDEC STANDARD MO-252 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y14.5M-2009
- 4.PIN ONE IDENTIFIER IS 2X LENGTH OF ANY
 - OTHER LINE IN THE MARK CODE LAYOUT.

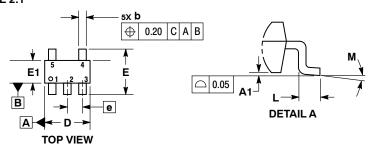
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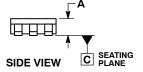
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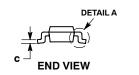




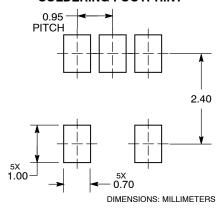
DATE 18 JAN 2018







RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- IES:
 DIMENSIONING AND TOLERANCING PER ASME
 Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH
 THICKNESS. MINIMUM LEAD THICKNESS IS THE
 MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

| | MILLIMETERS | | |
|-----|-------------|------|--|
| DIM | MIN | MAX | |
| Α | 0.90 | 1.10 | |
| A1 | 0.01 | 0.10 | |
| b | 0.25 | 0.50 | |
| С | 0.10 | 0.26 | |
| D | 2.85 | 3.15 | |
| E | 2.50 | 3.00 | |
| E1 | 1.35 | 1.65 | |
| е | 0.95 BSC | | |
| L | 0.20 | 0.60 | |
| М | 0 ° | 10° | |

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

Μ = Date Code = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ", may or may not be present. Some products may not follow the Generic Marking.

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|------------------|-------------|------------------------------------------------------------------------------------------------------------------------------------------------|-------------|
| DESCRIPTION: | SC-74A | | PAGE 1 OF 1 |

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SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

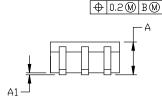
DATE 11 APR 2023

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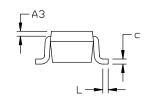
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE. NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

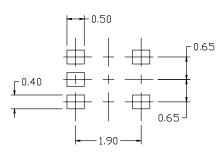
| DIM | MI | LLIMETE | RS |
|--------|------|----------|------|
| الملتط | MIN. | N□M. | MAX. |
| А | 0.80 | 0.95 | 1.10 |
| A1 | | | 0.10 |
| A3 | | 0.20 REF | - |
| b | 0.10 | 0.20 | 0.30 |
| С | 0.10 | | 0.25 |
| D | 1.80 | 2.00 | 2,20 |
| Е | 2.00 | 2.10 | 2.20 |
| E1 | 1.15 | 1.25 | 1.35 |
| е | | 0.65 BSI | С |
| L | 0.10 | 0.15 | 0.30 |

е Ε1 0



5X b





RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

out in the datasheet refer to the device

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

| STYLE 1 | • |
|---------|-----------|
| | EMITTER |
| | BASE |
| | COLLECTOR |
| 5. | COLLECTOR |

PIN 1. EMITTER 2

2. BASE 2

3. EMITTER 1

4. COLLECTOR

5. COLLECTOR 2/BASE 1

STYLE 6:

STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR CATHODE

2. EMITTER 3. BASE

4. COLLECTOR

5. COLLECTOR

STYLE 7:

PIN 1. BASE

STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1

PIN 1. CATHODE 2. COLLECTOR 3. N/C

4. BASE

STYLE 8:

STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3 SOURCE 1 4. GATE 1 5. GATE 2

3. ANODE 4. ANODE

STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4

STYLE 9: Note: Please refer to datasheet for PIN 1. ANODE 2. CATHODE style callout. If style type is not called

 ANODE
 ANODE datasheet pinout or pin assignment. 5. EMITTER Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.

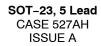
DOCUMENT NUMBER: 98ASB42984B **DESCRIPTION:** SC-88A (SC-70-5/SOT-353) PAGE 1 OF 1

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DATE 09 JUN 2021

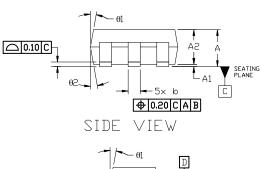
NOTES:

A

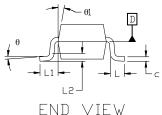
F1 F

В

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 19894
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS, MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED O. 25 PER SIDE. D AND E1 DIMENSIONS ARE DETERMINED AT DATUM D.
- 5. DIMENSION '6' DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08mm TOTAL IN EXCESS OF THE '6' DIMENSION AT MAXIMUM MATERIAL CONDITION. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL NOT BE LESS THAN 0.07mm.



TOP VIEW



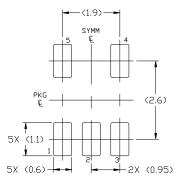
GENERIC MARKING DIAGRAM*



XXX = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

| | MILLIMETERS | | |
|-----|-------------|------|------|
| DIM | MIN. | N□M. | MAX. |
| Α | 0.90 | _ | 1.45 |
| A1 | 0.00 | _ | 0.15 |
| A2 | 0.90 | 1.15 | 1.30 |
| b | 0.30 | _ | 0.50 |
| С | 0.08 | _ | 0.22 |
| D | 2.90 BSC | | |
| Ε | 2.80 BSC | | |
| E1 | 1.60 BSC | | |
| е | 0.95 BSC | | |
| L | 0.30 | 0.45 | 0.60 |
| L1 | 0.60 REF | | |
| L2 | 0.25 REF | | |
| θ | 0° | 4° | 8* |
| θ1 | 0° | 10° | 15° |
| θ2 | 0* | 10° | 15° |



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

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